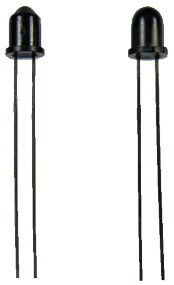
NPN Plastic Silicon Phototransistor

OP593, OP598, OP798 Series



Features:

- Dark blue epoxy package
- Wide receiving angle
- Variety of sensitivity ranges
- TO-18 equivalent package style

Description:

Each device in this series consists of an NPN silicon phototransistor molded in a dark blue epoxy packages. The wide receiving angle (130°) of the **OP593** series devices provides relatively even reception over a large area. The narrow receiving angle (25°) of the **OP598** and **OP798** series devices provides a relatively small reception area.

These devices are 100% production tested using infrared light for close correlation with OPTEK's GaAs and GaAlAs emitters.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

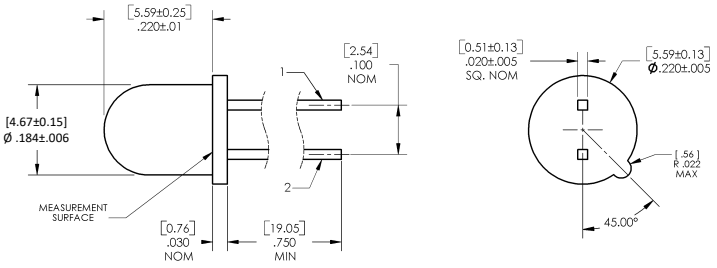
Applications:

- Non-contact reflective or slotted sensor
- Assembly line automation
- Machine automation
- Machine Safety
- End of travel sensor
- Door sensor
- Safety Curtain

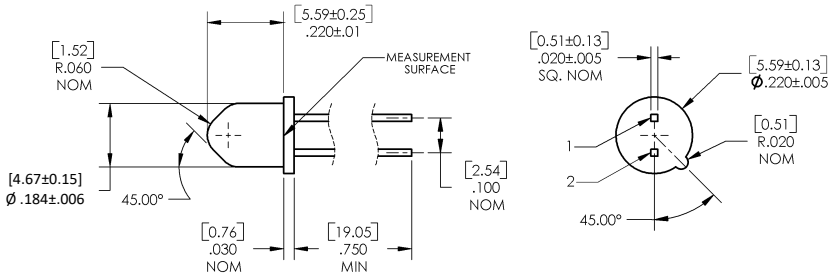
Pin #	Sensor
1	Collector
2	Emitter

Ordering Information			
Part Number	**Sensor**	**Viewing Angle**	**Lead Length**
OP593A	Transistor	130°	0.75"
OP593B			
OP593C			
OP598A		25°	
OP598B			
OP598C			
OP798A	R_{BE} Transistor	25°	
OP798B			
OP798C			
OP798D			

OP593



OP598, OP798



OP555 - CONTAINS POLYSULFONE

To avoid stress cracking, we suggest using ND Industries' **Vibra-Tite** for thread-locking. **Vibra-Tite** evaporates fast without causing structural failure in OPTEK'S molded plastics.

RoHS

DIMENSIONS ARE IN: **[MILLIMETERS]** **INCHES**

TT Electronics | OPTEK Technology
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)	
Storage and Operating Temperature Range	-40° C to +100° C
Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Continuous Collector Current	50 mA
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C(1)
Power Dissipation	250 mW(2)

Electrical Characteristics (T_A = 25° C unless otherwise noted)

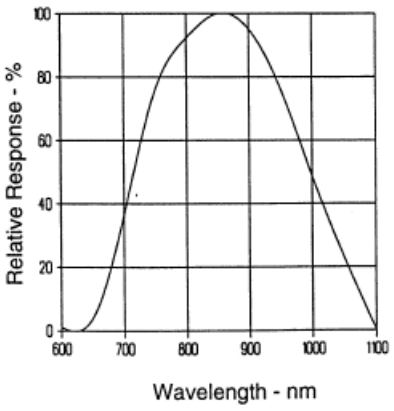
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
$I_{C(ON)}$	On-State Collector Current				mA	V_{CE} = 5 V. Light source is an unfiltered GaAlAs LED with a peak emission wavelength of 890 nm and $E_{e(APT)}$ of 1.7 mW/cm^2 average within a .250" diameter aperture.
	OP593A	3.0	-	4		
	OP593B	2.0	-	4		
	OP593C	1.0	-	4		
	OP598A	7.5	-	10		
	OP598B	5.0	-	10		
	OP598C	2.5	-	10		
	OP798A	4.90	-	15.00		
	OP798B	3.30	-	9.20		
	OP798C	1.90	-	6.10		
	OP798D	1.90	-	15.00		
I_{CEO}	Collector-Dark Current	-	-	100	nA	V_{CE} = 10 V, E_E = 0
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	I_C = 100 µA
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	I_E = 100 µA
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage	-	-	0.40	V	I_C = 0.4 mA, E_E = 1.7 mW/cm^2

TT Electronics | OPTEK Technology
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

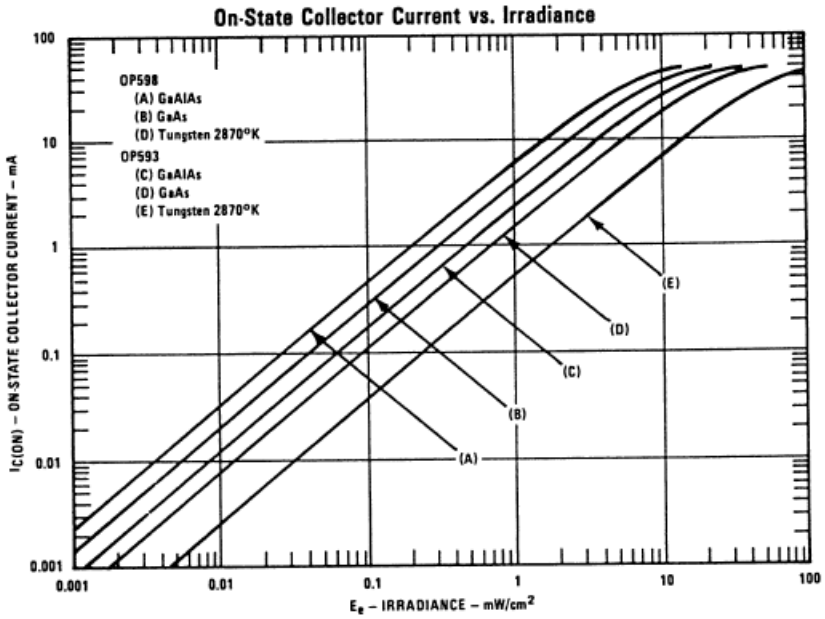
Performance

OP593, OP598

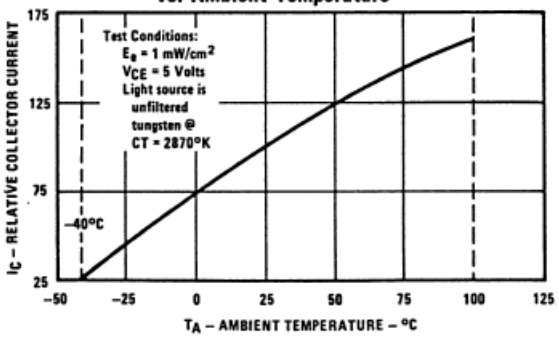
Typical Spectral Response



On-State Collector Current vs. Irradiance



Normalized Collector Current vs. Ambient Temperature

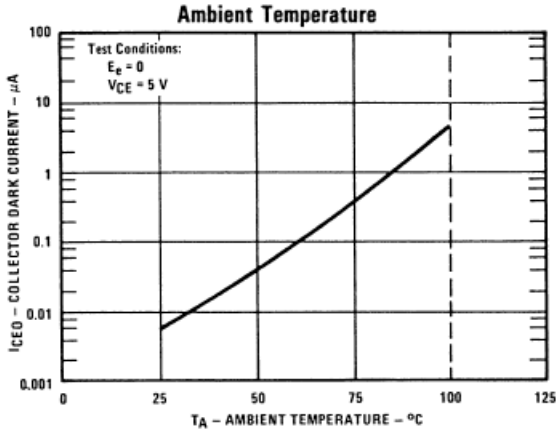


TT Electronics | OPTEK Technology
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

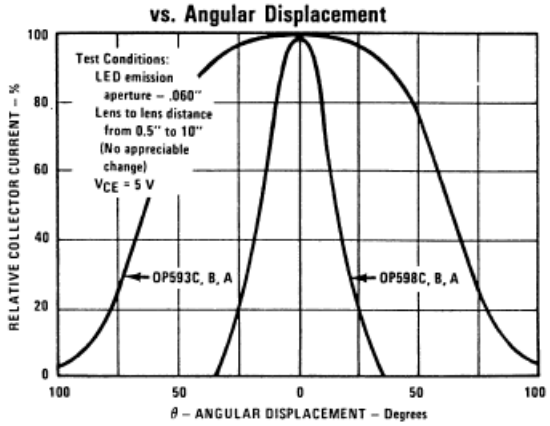
Performance

OP593, OP598

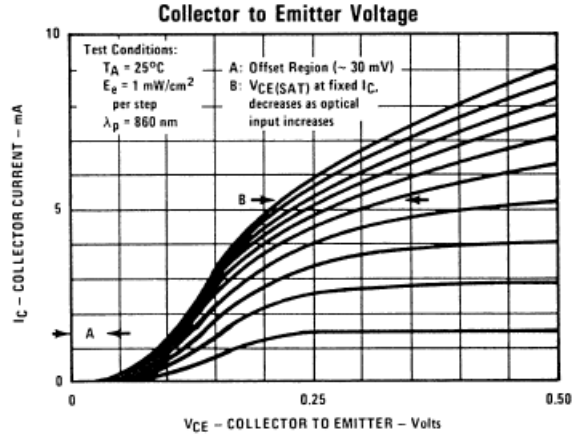
Collector Dark Current vs. Ambient Temperature



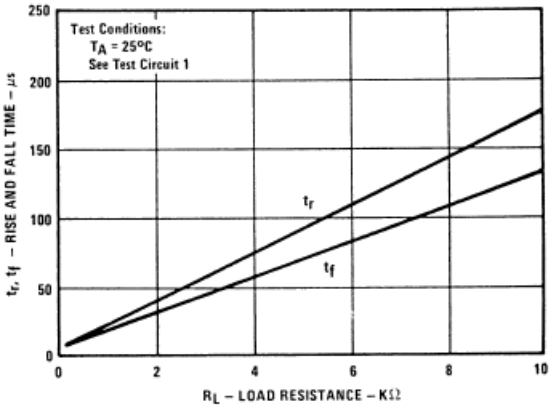
Relative Collector Current vs. Angular Displacement



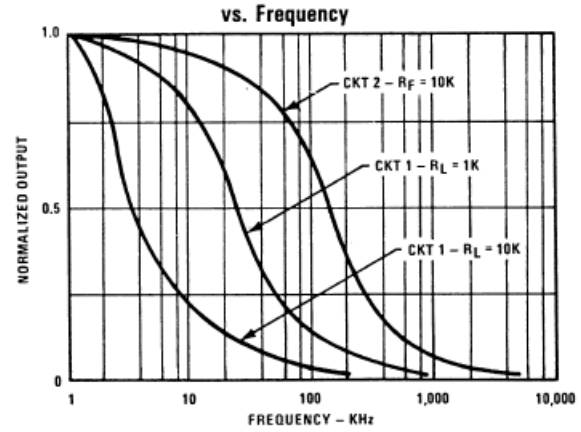
Collector Current vs. Collector to Emitter Voltage



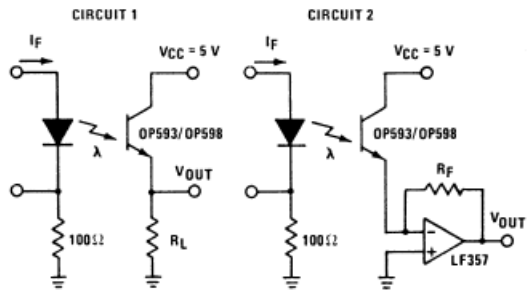
Rise and Fall Time vs. Load Resistance



Normalized Output vs. Frequency



Switching Time Test Circuit



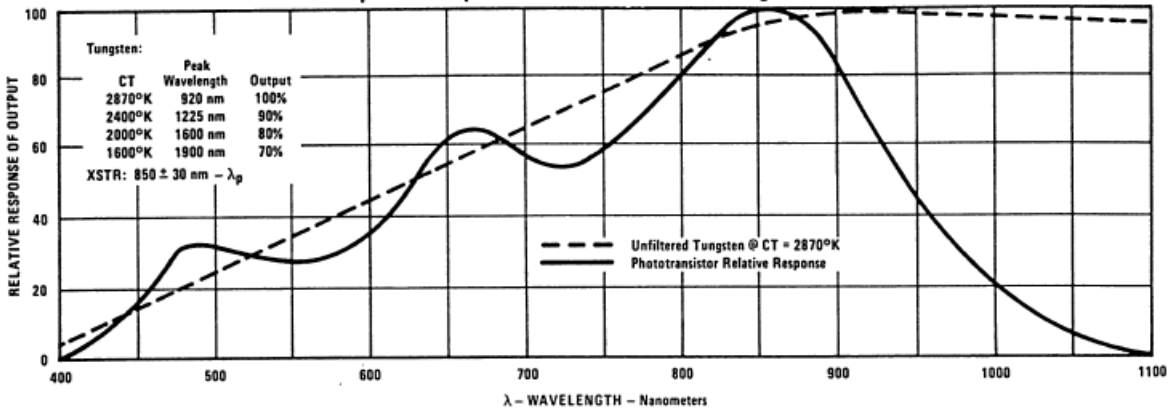
Test Conditions:
Light source is pulsed LED with t_r and $t_f \leq 500$ ns.
I_F is adjusted for V_{OUT} = 1 Volt.

TT Electronics | OPTEK Technology
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

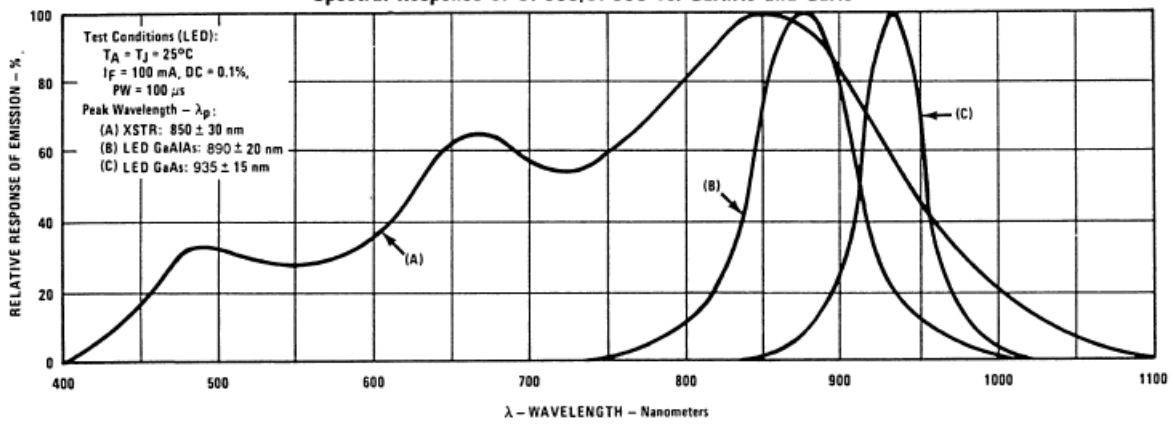
Performance

OP593, OP598

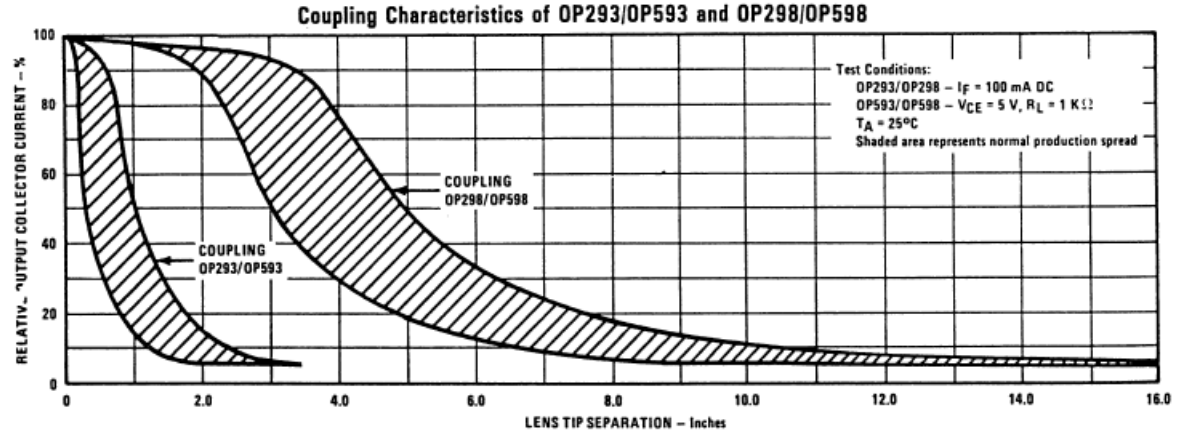
Spectral Response of OP593/OP598 vs. Tungsten



Spectral Response of OP593/OP598 vs. GaAlAs and GaAs



Coupling Characteristics of OP293/OP593 and OP298/OP598

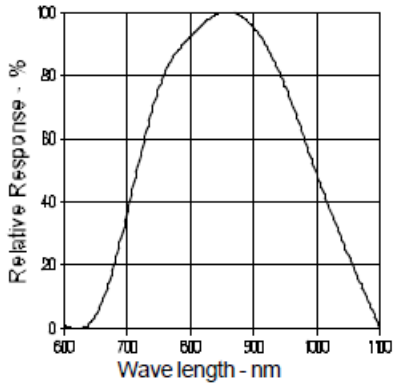


TT Electronics | OPTEK Technology
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

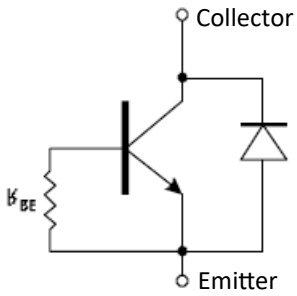
Performance

OP798

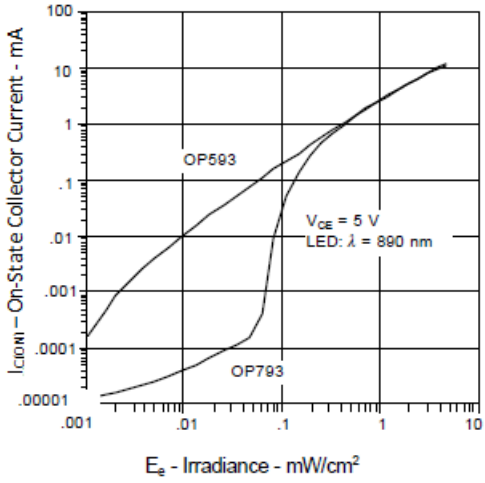
Typical Spectral Response



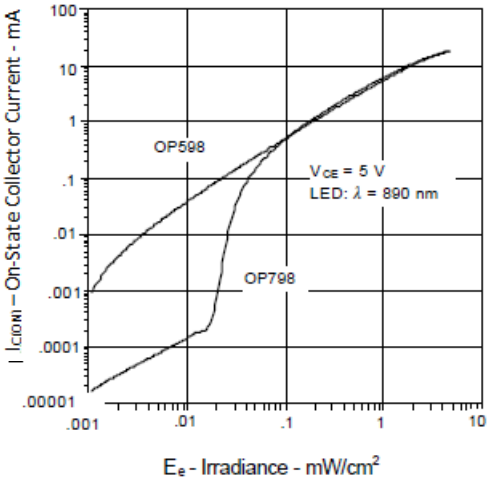
Schematic



On-State Collector Current vs. Irradiance



On-State Collector Current vs. Irradiance

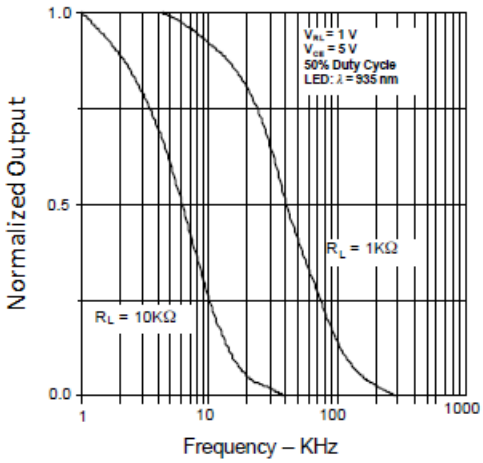


TT Electronics | OPTEK Technology
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

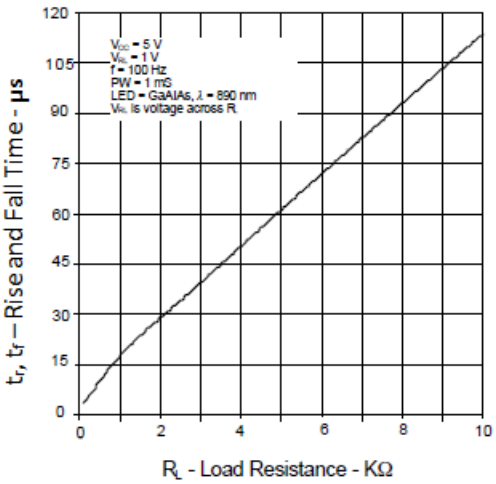
Performance

OP798

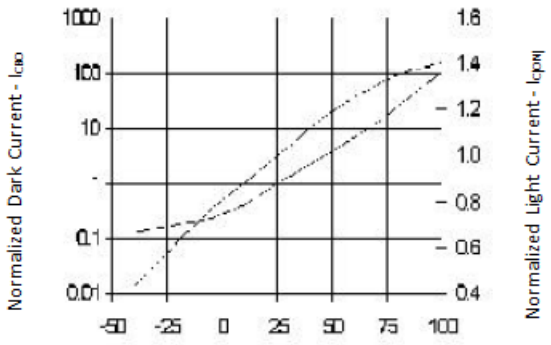
Normalized Output vs. Frequency



Typical Rise and Fall Time vs. Load Resistance



Normalized Light and Dark Current vs. Ambient Temperature



TT Electronics | OPTEK Technology
1645 Wallace Drive, Carrollton, TX 75006 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Phototransistors ***category:***

Click to view products by TT Electronics ***manufacturer:***

Other Similar products are found below :

LTR-5576D PT17-21B/L41/TR8 PT908-7B-F ASDL-6620-C22 OED-ST-8LR2 OED-STR44B90-TR SD5410-109 PT26-21C/CT PT15-21B-TR8 PT-IC-AC-3528-520 PT-IC-BC-3528-550 MHT153PTBT MHS153PTBT PT5529B/L2/H2-F PT91-21C/TR10 BP 103-3/4 BPX 38-3 BPY 62 KPS-3227SP1C L-53P3BT L-53P3C L-93DP3BT L-93DP3C LL-503PTC2E-1AD LL-S150PTC-1A LL-S150PTD-1A SFH 320 SFH 320-3 SFH 320 FA OP508FA TEMT1030 LTR-301 PGM5516 PGM5516-MP PGM5537-MP PGM5549 PGM5549-MP PGM5637D PGM5639D VTT7125H VEMT4700F-GS08 PT19-21B/L41/TR8 KP-2012P3C TEKT5400S SD1410-128L SFH 313 FA-2/3 SFH 320-4-Z SFH 309 FA-5/6 PT4800FE000F SFH 309-5/6